

MC14029B

Binary/Decade Up/Down Counter

The MC14029B Binary/Decade up/down counter is constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. The counter consists of type D flip-flop stages with a gating structure to provide toggle flip-flop capability. The counter can be used in either Binary or BCD operation. This complementary MOS counter finds primary use in up/down and difference counting and frequency synthesizer applications where low power dissipation and/or high noise immunity is desired. It is also useful in A/D and D/A conversion and for magnitude and sign generation.

Features

- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Internally Synchronous for High Speed
- Logic Edge-Clocked Design – Count Occurs on Positive Going Edge of Clock
- Asynchronous Preset Enable Operation
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range
- Pin for Pin Replacement for CD4029B
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- This Device is Pb-Free and is RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

| Symbol | Parameter | Value | Unit |
|-------------------|---|------------------------|------|
| V_{DD} | DC Supply Voltage Range | -0.5 to +18.0 | V |
| V_{in}, V_{out} | Input or Output Voltage Range (DC or Transient) | -0.5 to $V_{DD} + 0.5$ | V |
| I_{in}, I_{out} | Input or Output Current (DC or Transient) per Pin | ± 10 | mA |
| P_D | Power Dissipation, per Package (Note 1) | 500 | mW |
| T_A | Ambient Temperature Range | -55 to +125 | °C |
| T_{stg} | Storage Temperature Range | -65 to +150 | °C |
| T_L | Lead Temperature (8-Second Soldering) | 260 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C From 65°C To 125°C

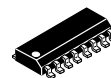
This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



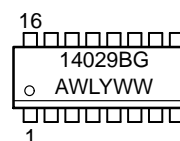
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SOIC-16
D SUFFIX
CASE 751B

MARKING DIAGRAM



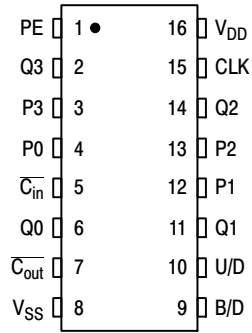
A = Assembly Location
WL = Wafer Lot
YY, Y = Year
WW = Work Week
G = Pb-Free Indicator

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

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PIN ASSIGNMENT



TRUTH TABLE

| Carry In | Up/Down | Preset Enable | Action |
|----------|---------|---------------|------------|
| 1 | X | 0 | No Count |
| 0 | 1 | 0 | Count Up |
| 0 | 0 | 0 | Count Down |
| X | X | 1 | Preset |

X = Don't Care

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|----------------------|--------------------------|
| MC14029BDR2G | SOIC-16 (Pb-Free) | 2500 Units / Tape & Reel |
| NLV14029BDR2G* | SOIC-16 (Pb-Free) | 2500 Units / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

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ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

| Characteristic | Symbol | V _{DD} Vdc | -55°C | | 25°C | | | 125°C | | Unit | |
|---|---|------------------------|--|-------|-------|-----------------|------|-------|-------|------|-----|
| | | | Min | Max | Min | Typ (Note 2) | Max | Min | Max | | |
| Output Voltage V _{in} = V _{DD} or 0 | "0" Level V _{OL} | 5.0 | – | 0.05 | – | 0 | 0.05 | – | 0.05 | Vdc | |
| | | 10 | – | 0.05 | – | 0 | 0.05 | – | 0.05 | | |
| | | 15 | – | 0.05 | – | 0 | 0.05 | – | 0.05 | | |
| | "1" Level V _{in} = 0 or V _{DD} | V _{OH} | 5.0 | 4.95 | – | 4.95 | 5.0 | – | 4.95 | – | Vdc |
| | | | 10 | 9.95 | – | 9.95 | 10 | – | 9.95 | – | |
| | | | 15 | 14.95 | – | 14.95 | 15 | – | 14.95 | – | |
| Input Voltage (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc) | "0" Level V _{IL} | 5.0 | – | 1.5 | – | 2.25 | 1.5 | – | 1.5 | Vdc | |
| | | 10 | – | 3.0 | – | 4.50 | 3.0 | – | 3.0 | | |
| | | 15 | – | 4.0 | – | 6.75 | 4.0 | – | 4.0 | | |
| | "1" Level (V _O = 0.5 or 4.5 Vdc) (V _O = 1.0 or 9.0 Vdc) (V _O = 1.5 or 13.5 Vdc) | V _{IH} | 5.0 | 3.5 | – | 3.5 | 2.75 | – | 3.5 | – | Vdc |
| | | | 10 | 7.0 | – | 7.0 | 5.50 | – | 7.0 | – | |
| | | | 15 | 11 | – | 11 | 8.25 | – | 11 | – | |
| Output Drive Current (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc) | Source I _{OH} | 5.0 | –3.0 | – | –2.4 | –4.2 | – | –1.7 | – | mAdc | |
| | | 5.0 | –0.64 | – | –0.51 | –0.88 | – | –0.36 | – | | |
| | | 10 | –1.6 | – | –1.3 | –2.25 | – | –0.9 | – | | |
| | Sink I _{OL} | 5.0 | 0.64 | – | 0.51 | 0.88 | – | 0.36 | – | mAdc | |
| | | 10 | 1.6 | – | 1.3 | 2.25 | – | 0.9 | – | | |
| | | 15 | 4.2 | – | 3.4 | 8.8 | – | 2.4 | – | | |
| Input Current | I _{in} | 15 | – | ±0.1 | – | ±0.00001 | ±0.1 | – | ±1.0 | μAdc | |
| Input Capacitance, (V _{in} = 0) | C _{in} | – | – | – | – | 5.0 | 7.5 | – | – | pF | |
| Quiescent Current (Per Package) | I _{DD} | 5.0 | – | 5.0 | – | 0.005 | 5.0 | – | 150 | μAdc | |
| | | 10 | – | 10 | – | 0.010 | 10 | – | 300 | | |
| | | 15 | – | 20 | – | 0.015 | 20 | – | 600 | | |
| Total Supply Current (Notes 3 & 4) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching) | I _T | 5.0 | I _T = (0.58 μA/kHz) f + I _{DD} | | | | | | | μAdc | |
| | | 10 | I _T = (1.20 μA/kHz) f + I _{DD} | | | | | | | | |
| | | 15 | I _T = (1.70 μA/kHz) f + I _{DD} | | | | | | | | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

3. The formulas given are for the typical characteristics only at 25°C.

4. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I_T is in μA (per package), C_L in pF, V = (V_{DD} – V_{SS}) in volts, f in kHz is input frequency, and k = 0.001.

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SWITCHING CHARACTERISTICS (Note 5) ($C_L = 50$ pF, $T_A = 25^\circ\text{C}$)

| Characteristic | Symbol | V_{DD} | All Types | | | Unit |
|--|----------------------------|-----------------|-------------------|-------------------|-------------------|---------------|
| | | | Min | Typ (Note 6) | Max | |
| Output Rise and Fall Time $t_{TLH}, t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{TLH}, t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{TLH}, t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$ | $t_{TLH},$ t_{THL} | 5.0 10 15 | – – – | 100 50 40 | 200 100 80 | ns |
| Propagation Delay Time Clk to Q $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 230 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 97 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 75 \text{ ns}$ | $t_{PLH},$ t_{PHL} | 5.0 10 15 | – – – | 200 100 90 | 400 200 180 | ns |
| Clk to $\overline{C_{out}}$ $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 230 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 97 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 75 \text{ ns}$ | $t_{PLH},$ t_{PHL} | 5.0 10 15 | – – – | 250 130 85 | 500 260 190 | ns |
| $\overline{C_{in}}$ to $\overline{C_{out}}$ $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 95 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 47 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 35 \text{ ns}$ | $t_{PLH},$ t_{PHL} | 5.0 10 15 | – – – | 175 50 50 | 360 120 100 | ns |
| PE to Q $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 230 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 97 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 75 \text{ ns}$ | $t_{PLH},$ t_{PHL} | 5.0 10 15 | – – – | 235 100 80 | 470 200 160 | ns |
| PE to $\overline{C_{out}}$ $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 465 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 192 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 125 \text{ ns}$ | $t_{PLH},$ t_{PHL} | 5.0 10 15 | – – – | 320 145 105 | 640 290 210 | ns |
| Clock Pulse Width | $t_{W(cl)}$ | 5.0 10 15 | 180 80 60 | 90 40 30 | – – – | ns |
| Clock Pulse Frequency | f_{cl} | 5.0 10 15 | – – – | 4.0 8.0 10 | 2.0 4.0 5.0 | MHz |
| Preset Removal Time The Preset Signal must be low prior to a positive-going transition of the clock. | t_{rem} | 5.0 10 15 | 160 80 60 | 80 40 30 | – – – | ns |
| Clock Rise and Fall Time | $t_{r(cl)}$ $t_{f(cl)}$ | 5.0 10 15 | – – – | – – – | 15 5 4 | μs |
| Carry In Setup Time | t_{su} | 5.0 10 15 | 150 60 40 | 75 30 20 | – – – | ns |
| Up/Down Setup Time | | 5.0 10 15 | 340 140 100 | 170 70 50 | – – – | ns |
| Binary/Decade Setup Time | | 5.0 10 15 | 320 140 100 | 160 70 50 | – – – | ns |
| Preset Enable Pulse Width | t_w | 5.0 10 15 | 130 70 50 | 65 35 25 | – – – | ns |

5. The formulas given are for the typical characteristics only at 25°C .

6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

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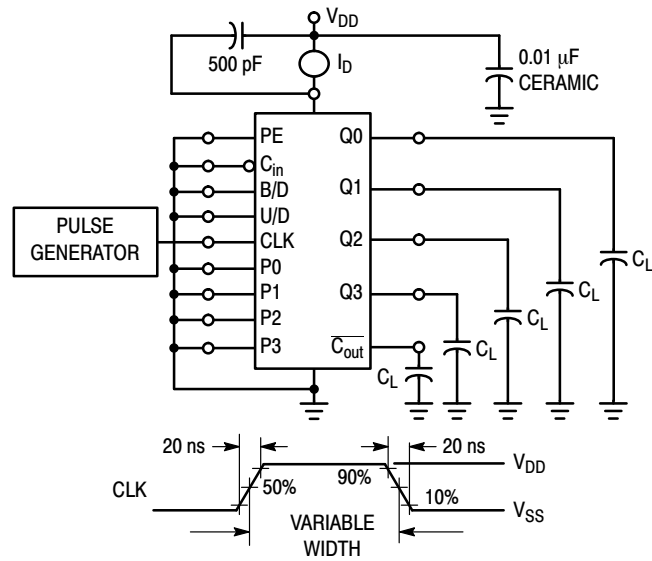


Figure 1. Power Dissipation Test Circuit and Waveform

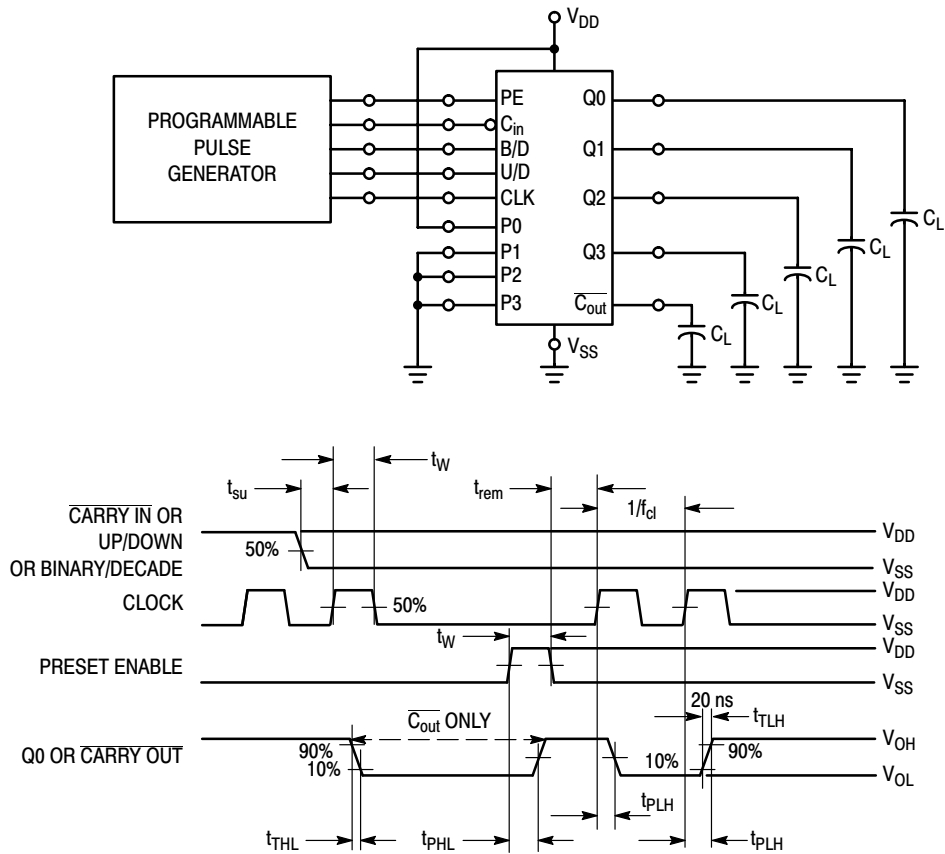
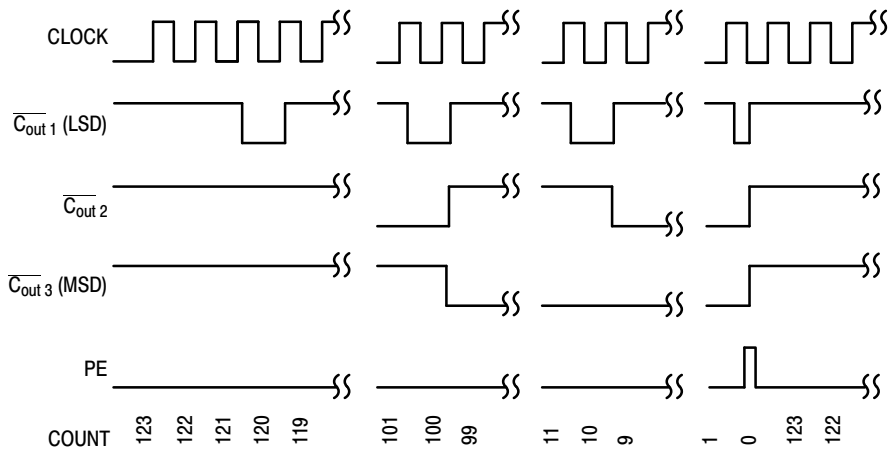
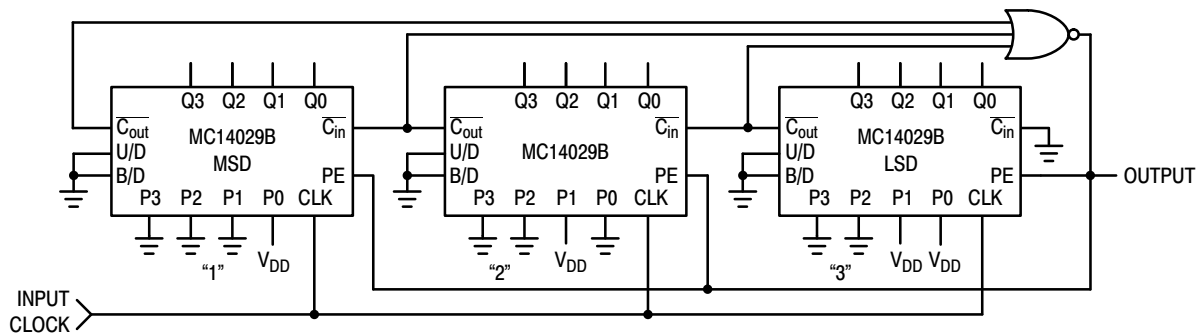
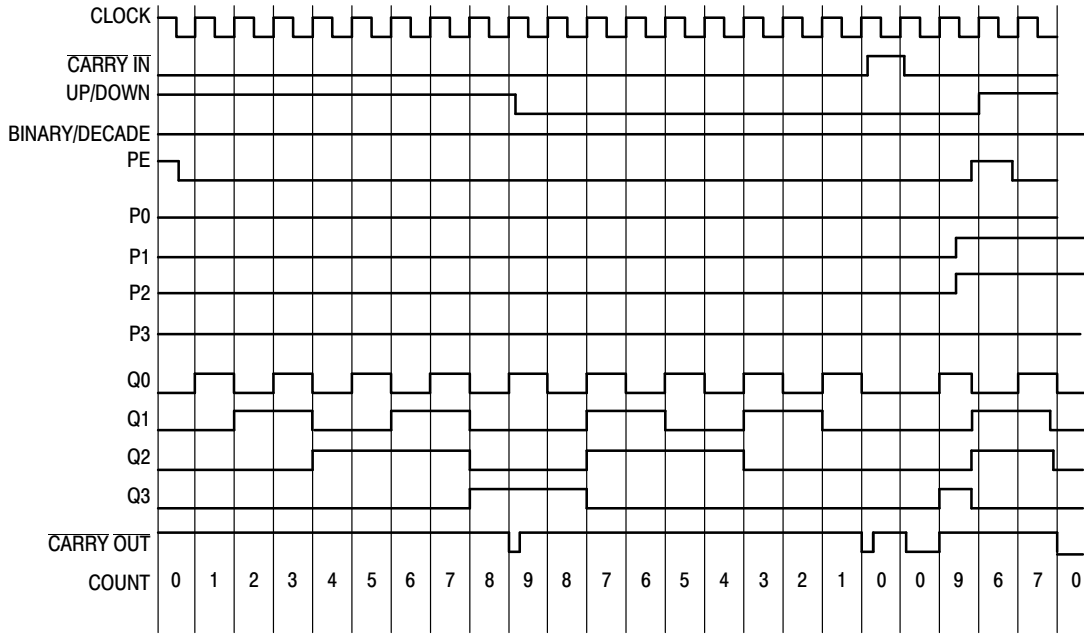


Figure 2. Switching Time Test Circuit and Waveforms

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TIMING DIAGRAM

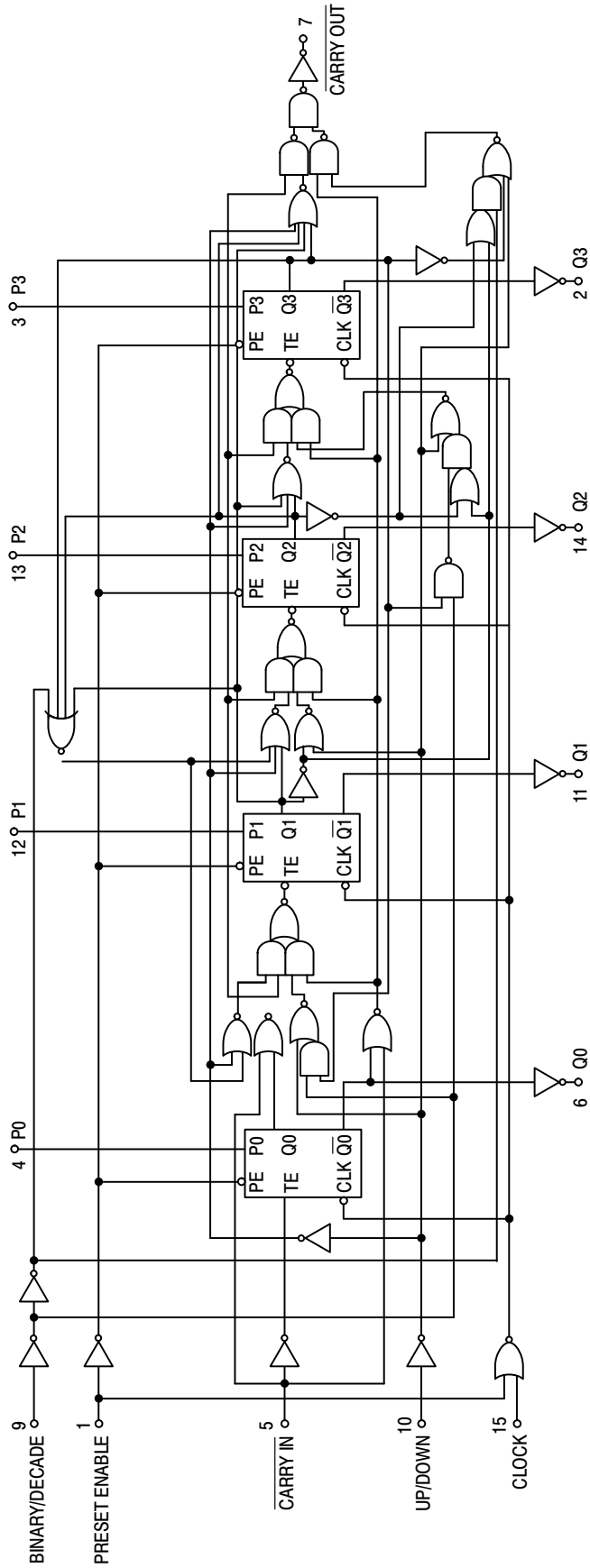


* $t_w \cong 900 \text{ ns} @ V_{DD} = 5 \text{ V}$

Figure 3. Divide by N BCD Down Counter and Timing Diagram (Shown for N = 123)

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LOGIC DIAGRAM



MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®



SCALE 1:1

SOIC-16 CASE 751B-05 ISSUE K

DATE 29 DEC 2006



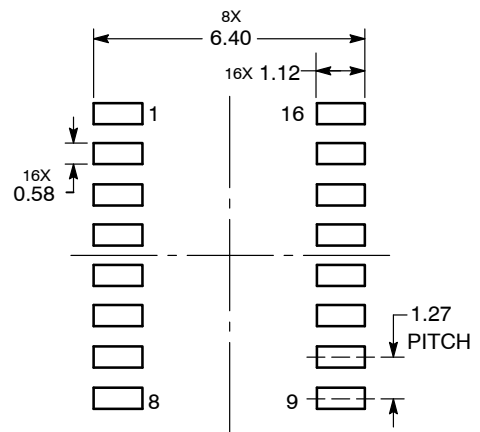
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 9.80 | 10.00 | 0.386 | 0.393 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 BSC | | 0.050 BSC | |
| J | 0.19 | 0.25 | 0.008 | 0.009 |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| M | 0° | 7° | 0° | 7° |
| P | 5.80 | 6.20 | 0.229 | 0.244 |
| R | 0.25 | 0.50 | 0.010 | 0.019 |

- | | | | |
|--|--|--|--|
| <p>STYLE 1:</p> <p>PIN 1. COLLECTOR</p> <p>2. BASE</p> <p>3. EMITTER</p> <p>4. NO CONNECTION</p> <p>5. EMITTER</p> <p>6. BASE</p> <p>7. COLLECTOR</p> <p>8. COLLECTOR</p> <p>9. BASE</p> <p>10. EMITTER</p> <p>11. NO CONNECTION</p> <p>12. EMITTER</p> <p>13. BASE</p> <p>14. COLLECTOR</p> <p>15. EMITTER</p> <p>16. COLLECTOR</p> | <p>STYLE 2:</p> <p>PIN 1. CATHODE</p> <p>2. ANODE</p> <p>3. NO CONNECTION</p> <p>4. CATHODE</p> <p>5. CATHODE</p> <p>6. NO CONNECTION</p> <p>7. ANODE</p> <p>8. CATHODE</p> <p>9. CATHODE</p> <p>10. ANODE</p> <p>11. NO CONNECTION</p> <p>12. CATHODE</p> <p>13. CATHODE</p> <p>14. NO CONNECTION</p> <p>15. ANODE</p> <p>16. CATHODE</p> | <p>STYLE 3:</p> <p>PIN 1. COLLECTOR, DYE #1</p> <p>2. BASE, #1</p> <p>3. EMITTER, #1</p> <p>4. COLLECTOR, #1</p> <p>5. COLLECTOR, #2</p> <p>6. BASE, #2</p> <p>7. EMITTER, #2</p> <p>8. COLLECTOR, #2</p> <p>9. COLLECTOR, #3</p> <p>10. BASE, #3</p> <p>11. EMITTER, #3</p> <p>12. COLLECTOR, #3</p> <p>13. COLLECTOR, #4</p> <p>14. BASE, #4</p> <p>15. EMITTER, #4</p> <p>16. COLLECTOR, #4</p> | <p>STYLE 4:</p> <p>PIN 1. COLLECTOR, DYE #1</p> <p>2. COLLECTOR, #1</p> <p>3. COLLECTOR, #2</p> <p>4. COLLECTOR, #2</p> <p>5. COLLECTOR, #3</p> <p>6. COLLECTOR, #3</p> <p>7. COLLECTOR, #4</p> <p>8. COLLECTOR, #4</p> <p>9. BASE, #4</p> <p>10. EMITTER, #4</p> <p>11. BASE, #3</p> <p>12. EMITTER, #3</p> <p>13. BASE, #2</p> <p>14. EMITTER, #2</p> <p>15. BASE, #1</p> <p>16. EMITTER, #1</p> |
| <p>STYLE 5:</p> <p>PIN 1. DRAIN, DYE #1</p> <p>2. DRAIN, #1</p> <p>3. DRAIN, #2</p> <p>4. DRAIN, #2</p> <p>5. DRAIN, #3</p> <p>6. DRAIN, #3</p> <p>7. DRAIN, #4</p> <p>8. DRAIN, #4</p> <p>9. GATE, #4</p> <p>10. SOURCE, #4</p> <p>11. GATE, #3</p> <p>12. SOURCE, #3</p> <p>13. GATE, #2</p> <p>14. SOURCE, #2</p> <p>15. GATE, #1</p> <p>16. SOURCE, #1</p> | <p>STYLE 6:</p> <p>PIN 1. CATHODE</p> <p>2. CATHODE</p> <p>3. CATHODE</p> <p>4. CATHODE</p> <p>5. CATHODE</p> <p>6. CATHODE</p> <p>7. CATHODE</p> <p>8. CATHODE</p> <p>9. ANODE</p> <p>10. ANODE</p> <p>11. ANODE</p> <p>12. ANODE</p> <p>13. ANODE</p> <p>14. ANODE</p> <p>15. ANODE</p> <p>16. ANODE</p> | <p>STYLE 7:</p> <p>PIN 1. SOURCE N-CH</p> <p>2. COMMON DRAIN (OUTPUT)</p> <p>3. COMMON DRAIN (OUTPUT)</p> <p>4. GATE P-CH</p> <p>5. COMMON DRAIN (OUTPUT)</p> <p>6. COMMON DRAIN (OUTPUT)</p> <p>7. COMMON DRAIN (OUTPUT)</p> <p>8. SOURCE P-CH</p> <p>9. SOURCE P-CH</p> <p>10. COMMON DRAIN (OUTPUT)</p> <p>11. COMMON DRAIN (OUTPUT)</p> <p>12. COMMON DRAIN (OUTPUT)</p> <p>13. GATE N-CH</p> <p>14. COMMON DRAIN (OUTPUT)</p> <p>15. COMMON DRAIN (OUTPUT)</p> <p>16. SOURCE N-CH</p> | |

SOLDERING FOOTPRINT



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